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**July 2011** 

## FDS86106

# N-Channel Power Trench<sup>®</sup> MOSFET 100 V, 3.4 A, 105 m $\Omega$

#### **Features**

- Max  $r_{DS(on)} = 105 \text{ m}\Omega$  at  $V_{GS} = 10 \text{ V}$ ,  $I_D = 3.4 \text{ A}$
- Max  $r_{DS(on)}$  = 171 m $\Omega$  at  $V_{GS}$  = 6 V,  $I_D$  = 2.7 A
- High performance trench technology for extremely low r<sub>DS(on)</sub>
- High power and current handling capability in a widely used surface mount package
- 100% UIL Tested
- RoHS Compliant

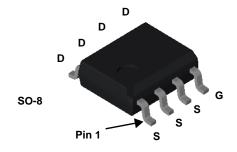


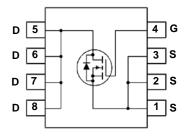
#### **General Description**

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench® process that has been optimized for  $r_{DS(on)}$ , switching performance and ruggedness.

#### **Applications**

- Synchronous Rectifier
- Primary Switch For Bridge Topology





### **MOSFET Maximum Ratings** $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Ratings	Units		
V <sub>DS</sub>	Drain to Source Voltage			100	V
$V_{GS}$	Gate to Source Voltage			±20	V
	Drain Current -Continuous			3.4	۸
ID	-Pulsed			15	Α
E <sub>AS</sub>	Single Pulse Avalanche Energy		(Note 3)	13	mJ
D	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	5.0	W
$P_{D}$	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1b)	2.5	VV
$T_J$ , $T_{STG}$	Operating and Storage Junction Temperature	Range		-55 to +150	°C

#### **Thermal Characteristics**

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Note 1)	2.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/VV

#### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS86106	FDS86106	SO-8	13 "	12 mm	2500 units

## **Electrical Characteristics** $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, referenced to 25 °C		67		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 80 V, V <sub>GS</sub> = 0 V			1	μА
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

#### **On Characteristics**

V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	2	2.9	4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, referenced to 25 °C		-9		mV/°C
		$V_{GS} = 10 \text{ V}, I_D = 3.4 \text{ A}$		83	105	
r <sub>DS(on)</sub>	Static Drain to Source On Resistance	$V_{GS} = 6 \text{ V}, I_D = 2.7 \text{ A}$		115	171	mΩ
, ,		$V_{GS} = 10 \text{ V}, I_D = 3.4 \text{ A}, T_J = 125 \text{ °C}$		143	177	
g <sub>FS</sub>	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_{D} = 3.4 \text{ A}$		6		S

#### **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V 50.V.V. 0.V.	156	208	pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1 \text{ MHz}$	47	62	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 1 1/11/12	2	3	pF
$R_g$	Gate Resistance		0.9		Ω

#### **Switching Characteristics**

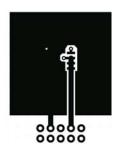
t <sub>d(on)</sub>	Turn-On Delay Time		5	10	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 50 V, I <sub>D</sub> = 3.4 A,	2	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$	8	15	ns
t <sub>f</sub>	Fall Time		2	10	ns
0	Total Gate Charge	V <sub>GS</sub> = 0 V to 10 V	3	4	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0 \text{ V to 5 V}$ $V_{DD} = 50 \text{ V}$	1.6	2.3	nC
$Q_{gs}$	Total Gate Charge	I <sub>D</sub> = 3.4 A	0.8		nC
$Q_{gd}$	Gate to Drain "Miller" Charge		0.8		nC

#### **Drain-Source Diode Characteristics**

1 Vob Source to Drain Diode Forward Voltage	Source to Drain Diode, Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 3.4 \text{ A}$ (Note 2)		0.86	1.3	V
	$V_{GS} = 0 \text{ V}, I_{S} = 2.1 \text{ A}$ (Note 2)		0.83	1.2	•	
t <sub>rr</sub>	Reverse Recovery Time			34	54	ns
Q <sub>rr</sub>	Reverse Recovery Charge			22	35	nC

#### NOTES

<sup>1.</sup> R<sub>BJA</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>BJC</sub> is guaranteed by design while R<sub>BCA</sub> is determined by the user's board design.



a) 50 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



b) 125 °C/W when mounted on a minimum pad.

- 2. Pulse Test: Pulse Width < 300  $\mu s,$  Duty cycle < 2.0 %.
- 3. Starting  $T_J$  = 25  $^oC;$  N-ch: L = 3 mH,  $I_{AS}$  = 3 A,  $V_{DD}$  = 100 V,  $V_{GS}$  = 10 V.

#### Typical Characteristics T<sub>J</sub> = 25 °C unless otherwise noted

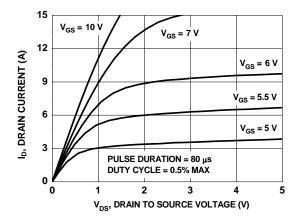


Figure 1. On-Region Characteristics

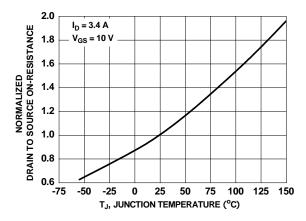


Figure 3. Normalized On-Resistance vs Junction Temperature

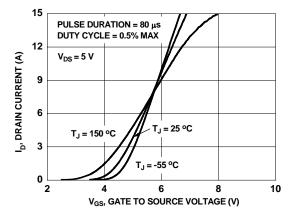


Figure 5. Transfer Characteristics

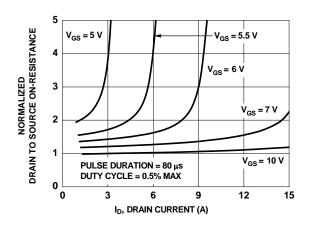


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

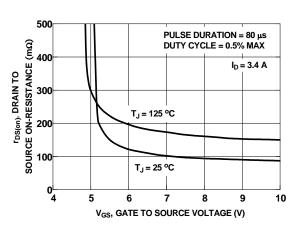


Figure 4. On-Resistance vs Gate to Source Voltage

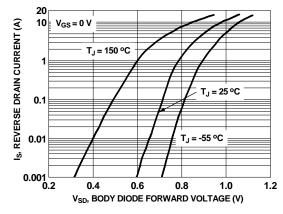


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

#### **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

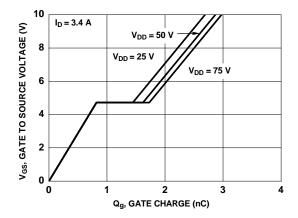


Figure 7. Gate Charge Characteristics

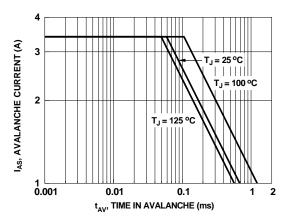


Figure 9. Unclamped Inductive Switching Capability

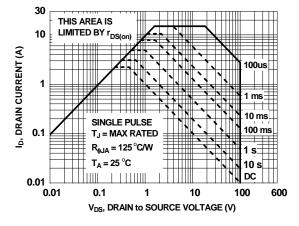


Figure 11. Forward Bias Safe Operating Area

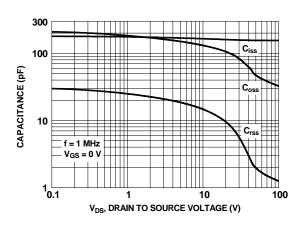


Figure 8. Capacitance vs Drain to Source Voltage

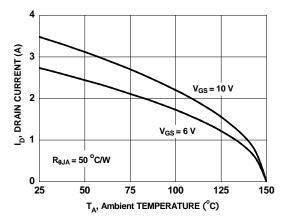


Figure 10. Maximum Continuous Drain Current vs Ambient Temperature

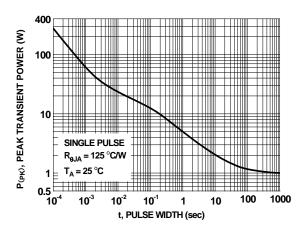


Figure 12. Single Pulse Maximum Power Dissipation

### **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

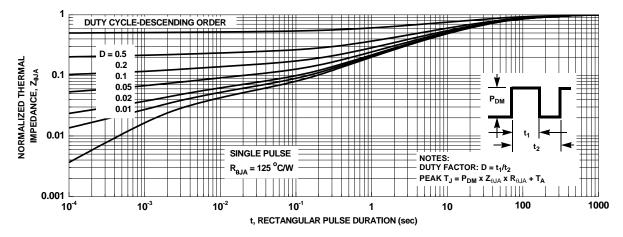


Figure 13. Junction-to-Ambient Transient Thermal Response Curve





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